

# 74LVC2G14

## Dual Inverter with 5V Tolerant Schmitt Trigger Inputs

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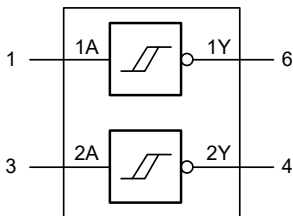
### GENERAL DESCRIPTION

The 74LVC2G14 contains two independent inverters each with Schmitt trigger input. They are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals. The 74LVC2G14 is designed for 1.65V to 5.5V  $V_{CC}$  operation. The device performs the Boolean function  $Y = \bar{A}$ .

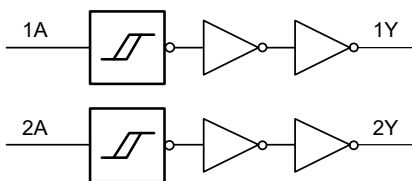
Inputs can be driven from either 3.3V or 5V devices. This feature allows the use of this device in a mixed 3.3V and 5V environment. Schmitt trigger action at the inputs makes the circuit tolerant of slower input rise and fall times.

This device is fully specified for partial power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

### LOGIC SYMBOL



### LOGIC DIAGRAM



### FEATURES

- **Wide Supply Voltage Range: 1.65V to 5.5V**
- **5V Tolerant Inputs for Interfacing with 5V Logic**
- **High Noise Immunity**
- **$\pm 24\text{mA}$  Output Drive at  $V_{CC} = 3.0\text{V}$**
- **CMOS Low Power Consumption**
- **Direct Interface with TTL Levels**
- **Unlimited Rise and Fall Times**
- **Inputs Accept Voltages up to 5V**
- **$-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$  Operating Temperature Range**
- **Available in a Green SC70-6 Package**

### FUNCTIONAL TABLE

INPUT	OUTPUT
nA	nY
L	H
H	L

$$Y = \bar{A}$$

H = High Voltage Level

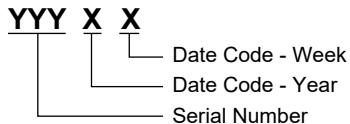
L = Low Voltage Level

## PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
74LVC2G14	SC70-6	-40°C to +125°C	74LVC2G14XC6G/TR	R55XX	Tape and Reel, 3000

## MARKING INFORMATION

NOTE: XX = Date Code.



Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS <sup>(1)</sup>

Supply Voltage, $V_{CC}$	-0.5V to 6.5V
Input Voltage, $V_I$ <sup>(2)</sup>	-0.5V to 6.5V
Output Voltage, $V_O$ <sup>(2)</sup>	
Active Mode	-0.5V to $V_{CC} + 0.5V$
Power-Down Mode, $V_{CC} = 0V$	-0.5V to 6.5V
Input Clamping Current, $I_{IK}$ ( $V_I < 0V$ )	-50mA
Output Clamping Current, $I_{OK}$ ( $V_O > V_{CC}$ or $V_O < 0V$ )	
	$\pm 50mA$
Output Current, $I_O$ ( $V_O = 0V$ to $V_{CC}$ )	$\pm 50mA$
Supply Current, $I_{CC}$	100mA
Ground Current, $I_{GND}$	-100mA
Junction Temperature <sup>(3)</sup>	+150°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (Soldering, 10s)	+260°C
ESD Susceptibility	
HBM	8000V
CDM	1000V

## RECOMMENDED OPERATING CONDITIONS

Supply Voltage, $V_{CC}$	1.65V to 5.5V
Input Voltage, $V_I$	0V to 5.5V
Output Voltage, $V_O$	
Active Mode	0V to $V_{CC}$
Power-Down Mode, $V_{CC} = 0V$	0V to 5.5V
Input Transition Rise and Fall Rate, $\Delta t/\Delta V$	
$V_{CC} = 1.65V$ to $2.7V$	20ns/V (MAX)
$V_{CC} = 2.7V$ to $5.5V$	10ns/V (MAX)
Operating Temperature Range	-40°C to +125°C

## OVERSTRESS CAUTION

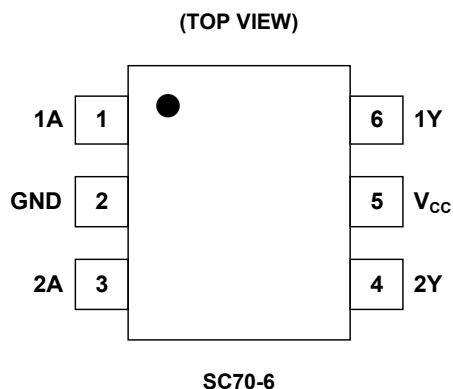
1. Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.
2. The input and output voltage ratings may be exceeded if the input and output clamp current ratings are observed.
3. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.

## ESD SENSITIVITY CAUTION

This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

## DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

**PIN CONFIGURATION****PIN DESCRIPTION**

PIN	NAME	FUNCTION
1, 3	1A, 2A	Data Inputs.
2	GND	Ground.
4, 6	2Y, 1Y	Data Outputs.
5	V <sub>CC</sub>	Supply Voltage.

**ELECTRICAL CHARACTERISTICS**(Full = -40°C to +125°C. All typical values are measured at maximum  $V_{CC}$  and  $T_A = +25^\circ\text{C}$ , unless stated noted.)

PARAMETER	SYMBOL	CONDITIONS	TEMP	MIN	TYP	MAX	UNITS	
High-Level Output Voltage	$V_{OH}$	$V_I = V_{T+}$ or $V_{T-}$	$I_O = -100\mu\text{A}$ , $V_{CC} = 1.65\text{V}$ to $5.5\text{V}$	Full	$V_{CC} - 0.05$	$V_{CC} - 0.01$	V	
			$I_O = -4\text{mA}$ , $V_{CC} = 1.65\text{V}$	Full	1.43	1.55		
			$I_O = -8\text{mA}$ , $V_{CC} = 2.3\text{V}$	Full	2.02	2.18		
			$I_O = -12\text{mA}$ , $V_{CC} = 2.7\text{V}$	Full	2.38	2.56		
			$I_O = -24\text{mA}$ , $V_{CC} = 3\text{V}$	Full	2.52	2.74		
			$I_O = -32\text{mA}$ , $V_{CC} = 4.5\text{V}$	Full	4	4.22		
Low-Level Output Voltage	$V_{OL}$	$V_I = V_{T+}$ or $V_{T-}$	$I_O = 100\mu\text{A}$ , $V_{CC} = 1.65\text{V}$ to $5.5\text{V}$	Full		0.01	0.05	V
			$I_O = 4\text{mA}$ , $V_{CC} = 1.65\text{V}$	Full		0.1	0.22	
			$I_O = 8\text{mA}$ , $V_{CC} = 2.3\text{V}$	Full		0.12	0.28	
			$I_O = 12\text{mA}$ , $V_{CC} = 2.7\text{V}$	Full		0.16	0.34	
			$I_O = 24\text{mA}$ , $V_{CC} = 3\text{V}$	Full		0.3	0.56	
			$I_O = 32\text{mA}$ , $V_{CC} = 4.5\text{V}$	Full		0.32	0.6	
Input Leakage Current	$I_I$	$V_I = 5.5\text{V}$ or GND, $V_{CC} = 0\text{V}$ to $5.5\text{V}$	Full		$\pm 0.01$	$\pm 1$	$\mu\text{A}$	
Power-Off Leakage Current	$I_{OFF}$	$V_I$ or $V_O = 5.5\text{V}$ , $V_{CC} = 0\text{V}$	Full		$\pm 0.01$	$\pm 1$	$\mu\text{A}$	
Supply Current	$I_{CC}$	$V_I = 5.5\text{V}$ or GND, $V_{CC} = 1.65\text{V}$ to $5.5\text{V}$ , $I_O = 0\text{A}$	Full		0.01	1	$\mu\text{A}$	
Additional Supply Current <sup>(1)</sup>	$\Delta I_{CC}$	$V_I = V_{CC} - 0.6\text{V}$ , $I_O = 0\text{A}$ , $V_{CC} = 2.3\text{V}$ to $5.5\text{V}$	Full		0.05	10	$\mu\text{A}$	
Input Capacitance	$C_I$	$V_{CC} = 3.3\text{V}$ , $V_I = \text{GND}$ to $V_{CC}$	+25°C		3		pF	

NOTE:

1. This is the increase in supply current for each input at the specified voltage level other than  $V_{CC}$  or GND.**DYNAMIC CHARACTERISTICS**(For test circuit, see Figure 4. Full = -40°C to +125°C, all typical values are measured at  $T_A = +25^\circ\text{C}$  and  $V_{CC} = 1.8\text{V}$ ,  $2.5\text{V}$ ,  $2.7\text{V}$ ,  $3.3\text{V}$  and  $5\text{V}$  respectively, unless stated noted.)

PARAMETER	SYMBOL	CONDITIONS	TEMP	MIN <sup>(1)</sup>	TYP	MAX <sup>(1)</sup>	UNITS	
Propagation Delay <sup>(2)</sup>	$t_{PD}$	nA to nY, see Figure 5	$V_{CC} = 1.65\text{V}$ to $1.95\text{V}$	Full	0.5	10.1	23.0	ns
			$V_{CC} = 2.3\text{V}$ to $2.7\text{V}$	Full	0.5	5.6	11.0	
			$V_{CC} = 2.7\text{V}$	Full	0.5	5.2	10.0	
			$V_{CC} = 3\text{V}$ to $3.6\text{V}$	Full	0.5	5.2	8.5	
			$V_{CC} = 4.5\text{V}$ to $5.5\text{V}$	Full	0.5	4.4	6.5	
Power Dissipation Capacitance <sup>(3)</sup>	$C_{PD}$	$V_I = \text{GND}$ to $V_{CC}$ , $V_{CC} = 3.3\text{V}$	+25°C		40		pF	

NOTES:

- Specified by design and characterization; not production tested.
- $t_{PD}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .
- $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$$

where:

 $f_i$  = Input frequency in MHz. $f_o$  = Output frequency in MHz. $C_L$  = Output load capacitance in pF. $V_{CC}$  = Supply voltage in Volts.

N = Number of inputs switching.

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = Sum of outputs.

**TRANSFER CHARACTERISTICS**

(Full = -40°C to +125°C. All typical values are measured at  $T_A = +25^\circ\text{C}$ , unless stated noted.)

PARAMETER	SYMBOL	CONDITIONS	TEMP	MIN	TYP	MAX	UNITS	
Positive-Going Threshold Voltage	$V_{T+}$	See Figure 1 and Figure 2	$V_{CC} = 1.8\text{V}$	Full	0.7	1.1	1.7	V
			$V_{CC} = 2.3\text{V}$	Full	1	1.4	2	
			$V_{CC} = 3\text{V}$ , see Figure 3	Full	1.3	1.76	2.4	
			$V_{CC} = 4.5\text{V}$	Full	1.9	2.47	3.3	
			$V_{CC} = 5.5\text{V}$	Full	2.2	2.91	3.8	
Negative-Going Threshold Voltage	$V_{T-}$	See Figure 1 and Figure 2	$V_{CC} = 1.8\text{V}$	Full	0.25	0.61	1.1	V
			$V_{CC} = 2.3\text{V}$	Full	0.4	0.8	1.35	
			$V_{CC} = 3\text{V}$ , see Figure 3	Full	0.6	1.04	1.7	
			$V_{CC} = 4.5\text{V}$	Full	1	1.55	2.2	
			$V_{CC} = 5.5\text{V}$	Full	1.2	1.86	2.5	
Hysteresis Voltage	$V_H$	$(V_{T+} - V_{T-})$ , See Figure 1 and Figure 2	$V_{CC} = 1.8\text{V}$	Full	0.15	0.49	1.2	V
			$V_{CC} = 2.3\text{V}$	Full	0.25	0.6	1.3	
			$V_{CC} = 3\text{V}$ , see Figure 3	Full	0.4	0.73	1.4	
			$V_{CC} = 4.5\text{V}$	Full	0.6	0.92	1.7	
			$V_{CC} = 5.5\text{V}$	Full	0.7	1.02	1.9	

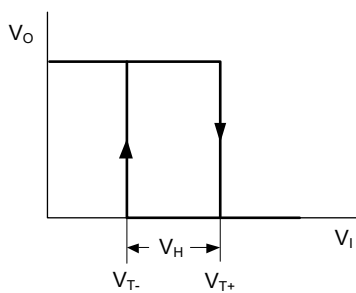


Figure 1. Transfer Characteristic

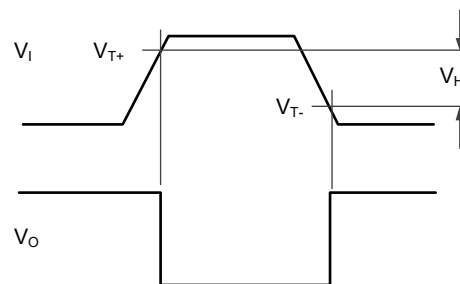


Figure 2. Definition of  $V_{T+}$ ,  $V_{T-}$ , and  $V_H$

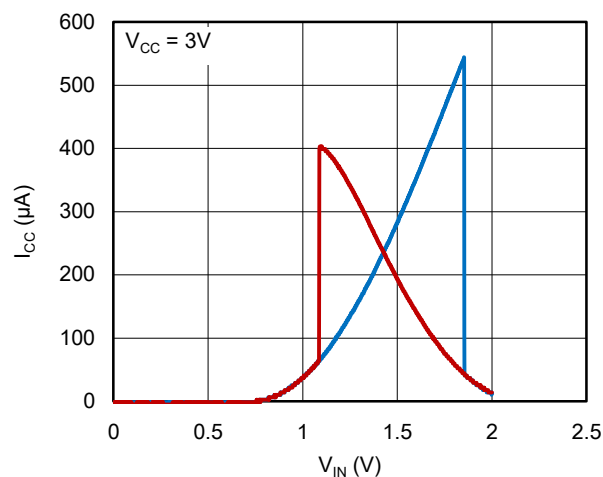
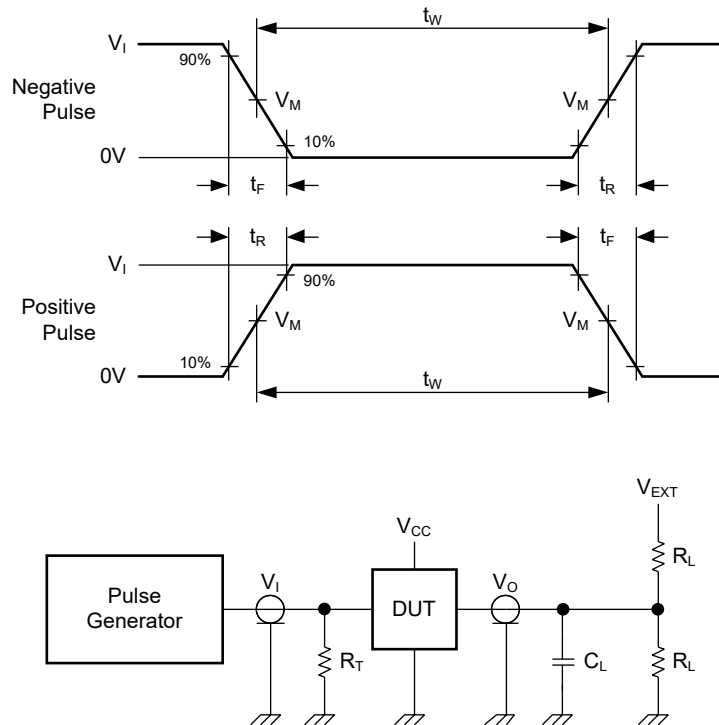


Figure 3. Typical Transfer Characteristics

## TEST CIRCUIT



Test conditions are given in Table 1.

Definitions for test circuit:

$R_L$  = Load resistance.

$C_L$  = Load capacitance including jig and probe capacitance.

$R_T$  = Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator.

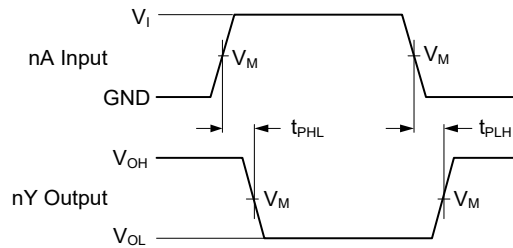
$V_{EXT}$  = External voltage for measuring switching times.

Figure 4. Test Circuit for Measuring Switching Times

Table 1. Test Conditions

SUPPLY VOLTAGE	INPUT		LOAD		$V_{EXT}$
$V_{CC}$	$V_I$	$t_R = t_F$	$C_L$	$R_L$	$t_{PLH}, t_{PHL}$
1.65V to 1.95V	$V_{CC}$	$\leq 2.0\text{ns}$	30pF	1k $\Omega$	Open
2.3V to 2.7V	$V_{CC}$	$\leq 2.0\text{ns}$	30pF	500 $\Omega$	Open
2.7V	2.7V	$\leq 2.5\text{ns}$	50pF	500 $\Omega$	Open
3.0V to 3.6V	2.7V	$\leq 2.5\text{ns}$	50pF	500 $\Omega$	Open
4.5V to 5.5V	$V_{CC}$	$\leq 2.5\text{ns}$	50pF	500 $\Omega$	Open

## WAVEFORMS



Test conditions are given in Table 1.

Measurement points are given in Table 2.

Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

Figure 5. The Data Input (nA) to Output (nY) Propagation Delays

Table 2. Measurement Points

SUPPLY VOLTAGE	INPUT	OUTPUT
$V_{CC}$	$V_M^{(1)}$	$V_M$
1.65V to 1.95V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
2.3V to 2.7V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
2.7V	1.5V	1.5V
3.0V to 3.6V	1.5V	1.5V
4.5V to 5.5V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$

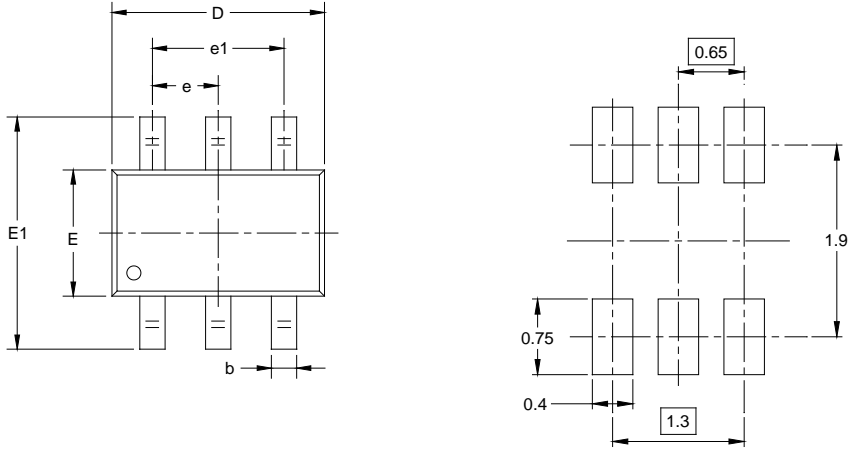
## NOTE:

- The measurement points should be  $V_{IH}$  or  $V_{IL}$  when the input rising or falling time exceeds 2.5ns.

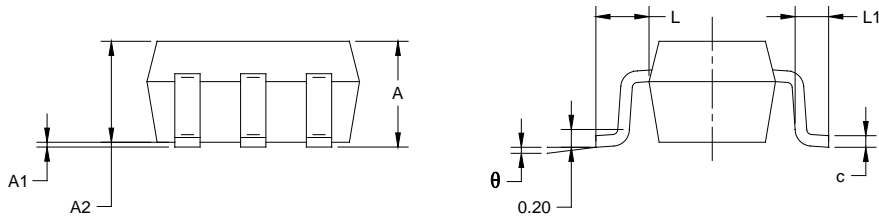
# PACKAGE INFORMATION

## PACKAGE OUTLINE DIMENSIONS

### SC70-6



RECOMMENDED LAND PATTERN (Unit: mm)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	0.800	1.100	0.031	0.043
A1	0.000	0.100	0.000	0.004
A2	0.800	1.000	0.031	0.039
b	0.150	0.350	0.006	0.014
c	0.080	0.220	0.003	0.009
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
e	0.65 TYP		0.026 TYP	
e1	1.300 BSC		0.051 BSC	
L	0.525 REF		0.021 REF	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°



# PACKAGE INFORMATION

## TAPE AND REEL INFORMATION

### REEL DIMENSIONS



### TAPE DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

### KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SC70-6	7"	9.5	2.40	2.50	1.20	4.0	4.0	2.0	8.0	Q3

DD0001

# PACKAGE INFORMATION

## CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

## KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
7" (Option)	368	227	224	8
7"	442	410	224	18

DD0002